

# H36SA54003

### 162W DC/DC Power Module





### H36SA54003, Half Brick Family DC/DC Power Modules: 18~75V in, 54V/3A out, 162W

The H36SA54003 Series, Half Brick, 18~75V input, single output, isolated DC/DC converter are the latest offering from a world leader in power systems technology and manufacturing — Delta Electronics, Inc. The H36SA54003 provide up to 162 watts of power in an industry standard footprint and pin out. With creative design technology and optimization of component placement, these converters possess outstanding electrical and thermal performances, as well as extremely high reliability under highly stressful operating conditions. The typical efficiency is 93.5% at 48V input, 54V output and 3A load.

#### **FEATURES**

- High efficiency: 93.5% @ 54V/3A
- Industry standard pin out and footprint
- Size: 61.0mm x 57.9mm x 13.2mm (2.40" x 2.28" x 0.52") with heat-spreader
- Fixed frequency operation
- Input UVLO
- Hiccup output over current protection (OCP)
- Hiccup output over voltage protection (OVP)
- Auto recovery OTP
- Monotonic startup into normal and pre-biased loads
- 2828V isolation and basic insulation
- No minimum load required
- ISO 9001, TL 9000, ISO 14001, QS9000, OHSAS18001 certified manufacturing facility
- IEC/EN/UL/CSA 62368-1, 2nd edition
- UL/cUL 60950-1 (US & Canada)

#### **OPTIONS**

- Negative or Positive remote On/Off
- Open frame/Heat spreader

#### Soldering method

- Hand soldering
- Wave soldering

#### **APPLICATIONS**

- Telecom / Datacom
- Wireless Networks
- Optical Network Equipment
- Server and Data Storage
- Industrial / Testing Equipment

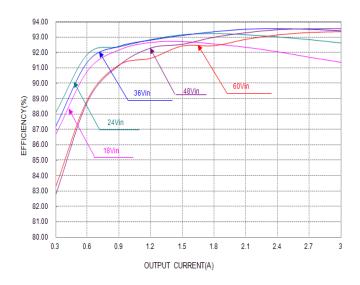


### **TECHNICAL SPECIFICATIONS**

(T<sub>A</sub>=25°C, airflow rate=300 LFM, V<sub>in</sub>=48Vdc, nominal Vout unless otherwise noted.)

ABSOLUTE MAXIMUM RATINGS         Input Voltage         Continuous         Transient (100ms)         Operating Ambient Temperature         Storage Temperature         Input/Output Isolation Voltage         INPUT CHARACTERISTICS         Operating Input Voltage Threshold         Turn-On Voltage Threshold         Turn-Of Voltage Threshold         Lockout Hysteresis Voltage         Maximum Input Current         No-Load Input Current         Off Converter Input Current         Input Voltage Ripple Rejection         OUTPUT CHARACTERISTICS         Output Voltage Ripple Rejection         OUTPUT CHARACTERISTICS         Output Voltage Ripple Rejection         Over Load         Output Voltage Ripple and Noise	Full Load, 18Vin Vin=48V, Io=0A Vin=48V, Io=0A Vin=48V, Io=0A P-P thru 12µH inductor, 5Hz to 20MHz 120 Hz Vin=48V, Io=Io.max, Tc=25°C Io=Io, min to Io, max Vin=18V to 75V Tc=-40°C to 85°C Over sample Ioad, line and temperature 5Hz to 20MHz bandwidth Vin=48V, Full Load, 10µF ceramic Vin=48V, Full Load, 10µF ceramic Vin=18V to 75V Output Voltage 10% Low 48Vin, 10µF ceramic, 0.1A/µs	Min. 0 -40 -55 18 16.0 15.0 0.3 52.92 52.38 52.38 0 0 3.3	Typ. 48 17.3 16.3 1 55 7 50 60 54.00 ±15 ±20 ±50 160 50	Max. 75 100 85 125 2828 75 18.0 17.0 1.8 11 1 1 55.08	Units Vdc Vdc °C °C Vdc Vdc Vdc Vdc Vdc Vdc Vdc Vdc
Input Voltage       Continuous         Transient (100ms)       Operating Ambient Temperature         Storage Temperature       Input/Output Isolation Voltage         Input/Output Isolation Voltage       Input/Output Isolation Voltage         Input/ CHARACTERISTICS       Operating Input Voltage Lockout         Turn-On Voltage Threshold       Input Voltage Threshold         Turn-Off Voltage Threshold       Input Current         No-Load Input Current       Maximum Input Current         Input Reflected-Ripple Rejection       Input Reflected-Ripple Rejection         Output Voltage Set Point       Output Voltage Range         Over Load       Over Load         Over Line       Over Comperature         Output Voltage Ripple and Noise       Peak-to-Peak         RMS       Operating Output Current Range         Output Voltage Current Transient       Positive Step Change in Output Current         Negative Step Change in Output Current       Negative Step Change in Output Current         Negative Step Change in Output Current       Start-Up Time, From Input         Output Capacitance       EFFICIENCY         100% Load       60% Load       60% Load	Vin=48V, lo=0A Vin=48V, lo=0A P-P thru 12µH inductor, 5Hz to 20MHz 120 Hz Vin=48V, lo=lo.max, Tc=25°C lo=lo, min to lo, max Vin=18V to 75V Tc=-40°C to 85°C Over sample load, line and temperature 5Hz to 20MHz bandwidth Vin=48V, Full Load, 10µF ceramic Vin=18V to 75V Output Voltage 10% Low 48Vin, 10µF ceramic, 0.1A/µs	-40 -55 18 16.0 15.0 0.3 52.92 52.38	17.3 16.3 1 55 7 50 60 54.00 ±15 ±20 ±50 160	100 85 125 2828 75 18.0 17.0 1.8 11 1 1 55.08	Vdc °C °C Vdc Vdc Vdc Vdc Vdc Vdc Vdc Vdc
Continuous         Transient (100ms)         Operating Ambient Temperature         Storage Temperature         Input/Output Isolation Voltage         Input/Output Isolation Voltage         Input/Output Isolation Voltage         Input/Output Isolation Voltage         Input Under-Voltage Lockout         Turn-On Voltage Threshold         Lockout Hysteresis Voltage         Maximum Input Current         No-Load Input Current         Off Converter Input Current         Input Voltage Rejection         OUTPUT CHARACTERISTICS         Output Voltage Rejection         OUTPUT CHARACTERISTICS         Output Voltage Rejection         Output Voltage Ripple and Noise         Peak-to-Peak         RMS         Operating Output Current Range         Output Voltage Current Transient         Positive Step Change in Output Current         Negative Step Change in Output Current	Vin=48V, lo=0A Vin=48V, lo=0A P-P thru 12µH inductor, 5Hz to 20MHz 120 Hz Vin=48V, lo=lo.max, Tc=25°C lo=lo, min to lo, max Vin=18V to 75V Tc=-40°C to 85°C Over sample load, line and temperature 5Hz to 20MHz bandwidth Vin=48V, Full Load, 10µF ceramic Vin=18V to 75V Output Voltage 10% Low 48Vin, 10µF ceramic, 0.1A/µs	-40 -55 18 16.0 15.0 0.3 52.92 52.38	17.3 16.3 1 55 7 50 60 54.00 ±15 ±20 ±50 160	100 85 125 2828 75 18.0 17.0 1.8 11 1 1 55.08	Vdc °C °C Vdc Vdc Vdc Vdc Vdc Vdc Vdc Vdc
Transient (100ms)         Operating Ambient Temperature         Storage Temperature         Input/Output Isolation Voltage         INPUT CHARACTERISTICS         Operating Input Voltage         Input Under-Voltage Lockout         Turn-On Voltage Threshold         Turn-Off Voltage Threshold         Lockout Hysteresis Voltage         Maximum Input Current         No-Load Input Current         Input Voltage Ripple Rejection         Off Converter Input Current         Input Voltage Ripple Rejection         OUTPUT CHARACTERISTICS         Output Voltage Ripple Rejection         Output Voltage Ripple and Noise         Peak-to-Peak         RMS         Operating Output Current Range         Output Voltage Ripple and Noise         Peak-to-Peak         RMS         Operating Output Current Range         Output Voltage Current Transient         Positive Step Change in Output Cur	Vin=48V, lo=0A Vin=48V, lo=0A P-P thru 12µH inductor, 5Hz to 20MHz 120 Hz Vin=48V, lo=lo.max, Tc=25°C lo=lo, min to lo, max Vin=18V to 75V Tc=-40°C to 85°C Over sample load, line and temperature 5Hz to 20MHz bandwidth Vin=48V, Full Load, 10µF ceramic Vin=18V to 75V Output Voltage 10% Low 48Vin, 10µF ceramic, 0.1A/µs	-40 -55 18 16.0 15.0 0.3 52.92 52.38	17.3 16.3 1 55 7 50 60 54.00 ±15 ±20 ±50 160	100 85 125 2828 75 18.0 17.0 1.8 11 1 1 55.08	Vdc °C Vdc Vdc Vdc Vdc Vdc Vdc Vdc A mA mA mA mA dB Vdc Wdc MV mV
Operating Ambient Temperature         Storage Temperature         Input/Output Isolation Voltage         INPUT CHARACTERISTICS         Operating Input Voltage         Input Under-Voltage Lockout         Turn-On Voltage Threshold         Lockout Hysteresis Voltage         Maximum Input Current         No-Load Input Current         No-Load Input Current         Inrush Current (I <sup>2</sup> t)         Input Reflected-Ripple Rejection         OUTPUT CHARACTERISTICS         Output Voltage Set Point         Output Voltage Range         Over Load         Output Voltage Range         Output Voltage Current Transient         Peak-to-Peak         RMS         Operating Output Current Range         Output Voltage Current Transient         Positive Step Change in Output Current         Negative Step Change in Output Current	Vin=48V, lo=0A Vin=48V, lo=0A P-P thru 12µH inductor, 5Hz to 20MHz 120 Hz Vin=48V, lo=lo.max, Tc=25°C lo=lo, min to lo, max Vin=18V to 75V Tc=-40°C to 85°C Over sample load, line and temperature 5Hz to 20MHz bandwidth Vin=48V, Full Load, 10µF ceramic Vin=18V to 75V Output Voltage 10% Low 48Vin, 10µF ceramic, 0.1A/µs	-55 18 16.0 15.0 0.3 52.92 52.38	17.3 16.3 1 55 7 50 60 54.00 ±15 ±20 ±50 160	125 2828 75 18.0 17.0 1.8 11 1 1 55.08	°C Vdc Vdc Vdc Vdc Vdc A mA mA a <sup>2</sup> s mA dB Vdc MV mV mV
Input/Output Isolation Voltage         INPUT CHARACTERISTICS         Operating Input Voltage         Input Under-Voltage Lockout         Turn-On Voltage Threshold         Lockout Hysteresis Voltage         Maximum Input Current         No-Load Input Current         Input Voltage Ripple Current         Input Voltage Ripple Rejection         OUTPUT CHARACTERISTICS         Output Voltage Ripple Rejection         Output Voltage Ripple Rejection         Over Load         Over Current Protection(hiccup mode)         Dynamic CHARACTERISTICS         Output Voltage Ripple and Noise         Peak-to-Peak         RMS         Operating Output Current Range         Output Voltage Current Transient         Positive Step Change in Output Current         Negative Step Change in Output Current         Negative Step Change in Output Current         Start-Up Time, From I	Vin=48V, lo=0A Vin=48V, lo=0A P-P thru 12µH inductor, 5Hz to 20MHz 120 Hz Vin=48V, lo=lo.max, Tc=25°C lo=lo, min to lo, max Vin=18V to 75V Tc=-40°C to 85°C Over sample load, line and temperature 5Hz to 20MHz bandwidth Vin=48V, Full Load, 10µF ceramic Vin=18V to 75V Output Voltage 10% Low 48Vin, 10µF ceramic, 0.1A/µs	18 16.0 15.0 0.3 52.92 52.38 52.38	$   \begin{array}{r}     17.3 \\     16.3 \\     1 \\     55 \\     7 \\     50 \\     60 \\     \hline     54.00 \\     \underline{+15} \\     \pm 20 \\     \pm 50 \\     \hline     160 \\   \end{array} $	2828 75 18.0 17.0 1.8 11 1 55.08	Vdc Vdc Vdc Vdc A mA mA A <sup>2</sup> s mA dB Vdc Vdc MV mV
INPUT CHARACTERISTICS         Operating Input Voltage         Input Under-Voltage Lockout         Turn-On Voltage Threshold         Turn-Off Voltage Threshold         Lockout Hysteresis Voltage         Maximum Input Current         No-Load Input Current         Inrush Current (Ift)         Input Reflected-Ripple Current         Input Reflected-Ripple Current         Input Voltage Ripple Rejection         OUTPUT CHARACTERISTICS         Output Voltage Ripple Rejection         Output Voltage Rage         Over Load         Over Current Protection(hiccup mode)         Dutput Voltage Ripple and Noise         Peak-to-Peak         RMS         Operating Output Current Range         Output Voltage Current Transient         Positive Step Change in Output Current         Negative Step Change in Output Current         Negative Step Change in Output Current         Settling Time, From Input         O	Vin=48V, lo=0A Vin=48V, lo=0A P-P thru 12µH inductor, 5Hz to 20MHz 120 Hz Vin=48V, lo=lo.max, Tc=25°C lo=lo, min to lo, max Vin=18V to 75V Tc=-40°C to 85°C Over sample load, line and temperature 5Hz to 20MHz bandwidth Vin=48V, Full Load, 10µF ceramic Vin=18V to 75V Output Voltage 10% Low 48Vin, 10µF ceramic, 0.1A/µs	16.0 15.0 0.3 52.92 52.38	$   \begin{array}{r}     17.3 \\     16.3 \\     1 \\     55 \\     7 \\     50 \\     60 \\     \hline     54.00 \\     \underline{+15} \\     \pm 20 \\     \pm 50 \\     \hline     160 \\   \end{array} $	75 18.0 17.0 1.8 11 1 55.08	Vdc Vdc Vdc A mA mA A <sup>2</sup> s mA dB Vdc Vdc Wdc
Operating Input Voltage         Input Under-Voltage Lockout         Turn-On Voltage Threshold         Turn-Off Voltage Threshold         Lockout Hysteresis Voltage         Maximum Input Current         No-Load Input Current         Inrush Current (1²t)         Input Reflected-Ripple Current         Input Noltage Ripple Rejection         Output Voltage Set Point         Output Voltage Ripple Range         Over Load         Output Voltage Ripple and Noise         Peak-to-Peak         RMS         Operating Output Current Range         Output Voltage Current Transient         Positive Step Change in Output Current         Negative Step Change in Output Current         Negative Step Change in Output Current         Settling Time (within 1% Vout nominal)         Turn-On Transient         Start-Up Time, From On/Off Control         Start-Up Time, From On/Off Control         Start-Up Time, From On/Off Control         Start-Up Time, From Input         Outpu	Vin=48V, lo=0A Vin=48V, lo=0A P-P thru 12µH inductor, 5Hz to 20MHz 120 Hz Vin=48V, lo=lo.max, Tc=25°C lo=lo, min to lo, max Vin=18V to 75V Tc=-40°C to 85°C Over sample load, line and temperature 5Hz to 20MHz bandwidth Vin=48V, Full Load, 10µF ceramic Vin=18V to 75V Output Voltage 10% Low 48Vin, 10µF ceramic, 0.1A/µs	16.0 15.0 0.3 52.92 52.38	$   \begin{array}{r}     17.3 \\     16.3 \\     1 \\     55 \\     7 \\     50 \\     60 \\     \hline     54.00 \\     \underline{+15} \\     \pm 20 \\     \pm 50 \\     \hline     160 \\   \end{array} $	18.0 17.0 1.8 11 1 1 55.08	Vdc Vdc A mA mA A <sup>2</sup> s mA dB Vdc Wdc mV mV
Input Under-Voltage Lockout           Turn-On Voltage Threshold           Turn-Off Voltage Threshold           Lockout Hysteresis Voltage           Maximum Input Current           No-Load Input Current           Off Converter Input Current           Inrush Current (1²t)           Input Reflected-Ripple Current           Input Reflected-Ripple Rejection           Output Voltage Ripple Rejection           Output Voltage Set Point           Output Voltage Range           Over Load           Over Load           Over Load           Over Load           Over Temperature           Total Output Voltage Range           Output Voltage Ripple and Noise           Peak-to-Peak           RMS           Operating Output Current Range           Output Voltage Current Transient           Positive Step Change in Output Current           Negative Step Change in Output Current           Negative Step Change in Output Current           Settling Time (within 1% Vout nominal)           Turn-On Transient           Start-Up Time, From On/Off Control           Start-Up Time, Fr	Vin=48V, lo=0A Vin=48V, lo=0A P-P thru 12µH inductor, 5Hz to 20MHz 120 Hz Vin=48V, lo=lo.max, Tc=25°C lo=lo, min to lo, max Vin=18V to 75V Tc=-40°C to 85°C Over sample load, line and temperature 5Hz to 20MHz bandwidth Vin=48V, Full Load, 10µF ceramic Vin=18V to 75V Output Voltage 10% Low 48Vin, 10µF ceramic, 0.1A/µs	16.0 15.0 0.3 52.92 52.38	$   \begin{array}{r}     17.3 \\     16.3 \\     1 \\     55 \\     7 \\     50 \\     60 \\     \hline     54.00 \\     \underline{+15} \\     \pm 20 \\     \pm 50 \\     \hline     160 \\   \end{array} $	18.0 17.0 1.8 11 1 1 55.08	Vdc Vdc A mA mA A <sup>2</sup> s mA dB Vdc Wdc mV mV
Turn-Off Voltage Threshold         Lockout Hysteresis Voltage         Maximum Input Current         No-Load Input Current         Off Converter Input Current         Inrush Current (1²t)         Input Voltage Ripple Rejection         OUTPUT CHARACTERISTICS         Output Voltage Set Point         Output Voltage Ripple Rejection         Over Load         Over Load         Over Load         Over Load         Over Temperature         Total Output Voltage Ripple and Noise         Peak-to-Peak         RMS         Output Voltage Current Range         Output Voltage Current Range         Output Voltage Current Transient         Positive Step Change in Output Current         Negative Step Change in Output Current         Negative Step Change in Output Current         Settling Time (within 1% Vout nominal)         Turn-On Transient         Start-Up Time, From Input         Output Capacitance         EFFICIENCY         100% Load         60% Load         Input to Output	Vin=48V, lo=0A Vin=48V, lo=0A P-P thru 12µH inductor, 5Hz to 20MHz 120 Hz Vin=48V, lo=lo.max, Tc=25°C lo=lo, min to lo, max Vin=18V to 75V Tc=-40°C to 85°C Over sample load, line and temperature 5Hz to 20MHz bandwidth Vin=48V, Full Load, 10µF ceramic Vin=18V to 75V Output Voltage 10% Low 48Vin, 10µF ceramic, 0.1A/µs	15.0 0.3 52.92 52.38	16.3 1 55 7 50 60 54.00 ±15 ±20 ±50 160	17.0 1.8 11 1 55.08	Vdc Vdc A mA mA A <sup>2</sup> s mA dB Vdc Vdc mV mV
Lockout Hysteresis Voltage         Maximum Input Current         No-Load Input Current         Off Converter Input Current         Inrush Current (I't)         Input Reflected-Ripple Current         Input Voltage Ripple Rejection         OUTPUT CHARACTERISTICS         Output Voltage Set Point         Output Regulation         Over Load         Over Load         Over Load         Over Load         Over Load         Over Ver Temperature         Total Output Voltage Range         Output Voltage Ripple and Noise         Peak-to-Peak         RMS         Operating Output Current Range         Output Voltage Current Transient         Positive Step Change in Output Current         Negative Step Change in Output Current         Negative Step Change in Output Current         Settling Time (within 1% Vout nominal)         Turn-On Transient         Start-Up Time, From On/Off Control         Start-Up Time, From Input         Output Capacitance         EFFICIENCY         100% Load         60% Load         Input to Output	Vin=48V, lo=0A Vin=48V, lo=0A P-P thru 12µH inductor, 5Hz to 20MHz 120 Hz Vin=48V, lo=lo.max, Tc=25°C lo=lo, min to lo, max Vin=18V to 75V Tc=-40°C to 85°C Over sample load, line and temperature 5Hz to 20MHz bandwidth Vin=48V, Full Load, 10µF ceramic Vin=18V to 75V Output Voltage 10% Low 48Vin, 10µF ceramic, 0.1A/µs	0.3 52.92 52.38	1 55 7 50 60 54.00 ±15 ±20 ±50	1.8 11 1 55.08	Vdc A mA mA A <sup>2</sup> s mA dB Vdc Vdc mV mV
Maximum Input Current         No-Load Input Current         Off Converter Input Current         Inrush Current ( I <sup>2</sup> t)         Input Reflected-Ripple Current         Input Voltage Ripple Rejection         OUTPUT CHARACTERISTICS         Output Voltage Set Point         Output Regulation         Over Load         Over Line         Over Line         Over Temperature         Total Output Voltage Range         Output Voltage Ripple and Noise         Peak-to-Peak         RMS         Operating Output Current Range         Output Voltage Current Protection(hiccup mode)         DYNAMIC CHARACTERISTICS         Output Voltage Current Transient         Positive Step Change in Output Current         Negative Step Change in Output Current         Settling Time (within 1% Vout nominal)         Turn-On Transient         Start-Up Time, From On/Off Control         Start-Up Time, From Input         Output Capacitance         EFFICIENCY         100% Load         60% Load         Input to Output	Vin=48V, lo=0A Vin=48V, lo=0A P-P thru 12µH inductor, 5Hz to 20MHz 120 Hz Vin=48V, lo=lo.max, Tc=25°C lo=lo, min to lo, max Vin=18V to 75V Tc=-40°C to 85°C Over sample load, line and temperature 5Hz to 20MHz bandwidth Vin=48V, Full Load, 10µF ceramic Vin=18V to 75V Output Voltage 10% Low 48Vin, 10µF ceramic, 0.1A/µs	52.92 52.38	55 7 50 60 54.00 ±15 ±20 ±50	11 1 55.08	A mA MA A <sup>2</sup> s mA dB Vdc Wdc Wdc WV mV
No-Load Input Current         Off Converter Input Current         Inrush Current (I <sup>2</sup> t)         Input Reflected-Ripple Current         Input Voltage Ripple Rejection         OUTPUT CHARACTERISTICS         Output Voltage Set Point         Output Regulation         Over Load         Over Line         Over Line         Over Temperature         Total Output Voltage Range         Output Voltage Ripple and Noise         Peak-to-Peak         RMS         Operating Output Current Range         Output Voltage Current Protection(hiccup mode)         DYNAMIC CHARACTERISTICS         Output Voltage Current Transient         Positive Step Change in Output Current         Negative Step Change in Output Current         Settling Time, From On/Off Control         Start-Up Time, From Input         Output Capacitance         EFFICIENCY         100% Load         60% Load         IsoLATION CHARACTERISTICS         Input to Output	Vin=48V, lo=0A Vin=48V, lo=0A P-P thru 12µH inductor, 5Hz to 20MHz 120 Hz Vin=48V, lo=lo.max, Tc=25°C lo=lo, min to lo, max Vin=18V to 75V Tc=-40°C to 85°C Over sample load, line and temperature 5Hz to 20MHz bandwidth Vin=48V, Full Load, 10µF ceramic Vin=18V to 75V Output Voltage 10% Low 48Vin, 10µF ceramic, 0.1A/µs	52.38	7 50 60 54.00 ±15 ±20 ±50	1 55.08	mA mA A <sup>2</sup> s mA dB Vdc Wdc mV mV
Off Converter Input Current         Inrush Current (1 <sup>2</sup> t)         Input Reflected-Ripple Current         Input Voltage Ripple Rejection         OUTPUT CHARACTERISTICS         Output Voltage Set Point         Output Voltage Set Point         Over Load         Over Line         Over Temperature         Total Output Voltage Ripple and Noise         Peak-to-Peak         RMS         Operating Output Current Range         Output Voltage Current Protection(hiccup mode)         DYNAMIC CHARACTERISTICS         Output Voltage Current Transient         Positive Step Change in Output Current         Negative Step Change in Output Current         Settling Time (within 1% Vout nominal)         Turn-On Transient         Start-Up Time, From Input         Output Capacitance         EFFICIENCY         100% Load         60% Load         IsoLATION CHARACTERISTICS         Input to Output	Vin=48V, Io=0A P-P thru 12µH inductor, 5Hz to 20MHz 120 Hz Vin=48V, Io=Io.max, Tc=25°C Io=Io, min to Io, max Vin=18V to 75V Tc=-40°C to 85°C Over sample Ioad, line and temperature 5Hz to 20MHz bandwidth Vin=48V, Full Load, 10µF ceramic Vin=48V, Full Load, 10µF ceramic Vin=18V to75V Output Voltage 10% Low 48Vin, 10µF ceramic, 0.1A/µs	52.38	7 50 60 54.00 ±15 ±20 ±50	55.08	mA A <sup>2</sup> s mA dB Vdc MV mV mV
Inrush Current (1 <sup>2</sup> t)         Input Reflected-Ripple Rejection         OUTPUT CHARACTERISTICS         Output Voltage Set Point         Output Regulation         Over Load         Over Line         Over Temperature         Total Output Voltage Range         Output Voltage Ripple and Noise         Peak-to-Peak         RMS         Output Voltage Ripple and Noise         Peak-to-Peak         RMS         Output Voltage Current Range         Output Voltage Current Protection(hiccup mode)         DYNAMIC CHARACTERISTICS         Output Voltage Current Transient         Positive Step Change in Output Current         Negative Step Change in Output Current         Settling Time (within 1% Vout nominal)         Turn-On Transient         Start-Up Time, From On/Off Control         Start-Up Time, From Input         Output Capacitance         EFFICIENCY         100% Load         60% Load         IsoLATION CHARACTERISTICS         Input to Output	P-P thru 12µH inductor, 5Hz to 20MHz 120 Hz Vin=48V, lo=lo.max, Tc=25°C lo=lo, min to lo, max Vin=18V to 75V Tc=-40°C to 85°C Over sample load, line and temperature 5Hz to 20MHz bandwidth Vin=48V, Full Load, 10µF ceramic Vin=48V, Full Load, 10µF ceramic Vin=18V to75V Output Voltage 10% Low 48Vin, 10µF ceramic, 0.1A/µs	52.38	60 54.00 ±15 ±20 ±50	55.08	A <sup>2</sup> s mA dB Vdc mV mV mV
Input Voltage Ripple Rejection         OUTPUT CHARACTERISTICS         Output Voltage Set Point         Output Regulation         Over Load         Over Line         Over Temperature         Total Output Voltage Range         Output Voltage Ripple and Noise         Peak-to-Peak         RMS         Output Voltage Ripple and Noise         Peak-to-Peak         RMS         Operating Output Current Range         Output Voltage Current Transient         Positive Step Change in Output Current         Negative Step Change in Output Current         Settling Time (within 1% Vout nominal)         Turn-On Transient         Start-Up Time, From On/Off Control         Start-Up Time, From Input         Output Capacitance         EFFICIENCY         100% Load         60% Load         IsoLATION CHARACTERISTICS         Input to Output	120 Hz         Vin=48V, lo=lo.max, Tc=25°C         lo=lo, min to lo, max         Vin=18V to 75V         Tc=-40°C to 85°C         Over sample load, line and temperature         5Hz to 20MHz bandwidth         Vin=48V, Full Load, 10µF ceramic         Vin=48V, Full Load, 10µF ceramic         Vin=18V to75V         Output Voltage 10% Low         48Vin, 10µF ceramic, 0.1A/µs	52.38	60 54.00 ±15 ±20 ±50		dB Vdc mV mV mV
OUTPUT CHARACTERISTICS         Output Voltage Set Point         Output Regulation         Over Load         Over Line         Over Temperature         Total Output Voltage Range         Output Voltage Ripple and Noise         Peak-to-Peak         RMS         Output Voltage Current Protection(hiccup mode)         DYNAMIC CHARACTERISTICS         Output Voltage Current Transient         Positive Step Change in Output Current         Negative Step Change in Output Current         Settling Time (within 1% Vout nominal)         Turn-On Transient         Start-Up Time, From On/Off Control         Start-Up Time, From Input         Output Capacitance         EFFICIENCY         100% Load         60% Load         Boy Load         Input to Output	Vin=48V, lo=lo.max, Tc=25°C lo=lo, min to lo, max Vin=18V to 75V Tc=-40°C to 85°C Over sample load, line and temperature 5Hz to 20MHz bandwidth Vin=48V, Full Load, 10µF ceramic Vin=48V, Full Load, 10µF ceramic Vin=18V to75V Output Voltage 10% Low 48Vin, 10µF ceramic, 0.1A/µs	52.38	54.00 ±15 ±20 ±50 160		Vdc mV mV mV
Output Voltage Set Point         Output Regulation         Over Load         Over Line         Over Temperature         Total Output Voltage Range         Output Voltage Ripple and Noise         Peak-to-Peak         RMS         Operating Output Current Range         Output Voltage Current Protection(hiccup mode)         DYNAMIC CHARACTERISTICS         Output Voltage Current Transient         Positive Step Change in Output Current         Negative Step Change in Output Current         Settling Time (within 1% Vout nominal)         Turn-On Transient         Start-Up Time, From On/Off Control         Start-Up Time, From Input         Output Capacitance         EFFICIENCY         100% Load         60% Load         IsoLATION CHARACTERISTICS         Input to Output	lo=lo, min to lo, max Vin=18V to 75V Tc=-40°C to 85°C Over sample load, line and temperature 5Hz to 20MHz bandwidth Vin=48V, Full Load, 10µF ceramic Vin=48V, Full Load, 10µF ceramic Vin=18V to75V Output Voltage 10% Low 48Vin, 10µF ceramic, 0.1A/µs	52.38	±15 ±20 ±50		mV mV mV
Output Regulation         Over Load         Over Line         Over Temperature         Total Output Voltage Range         Output Voltage Ripple and Noise         Peak-to-Peak         RMS         Operating Output Current Range         Output Voltage Current Protection(hiccup mode)         DYNAMIC CHARACTERISTICS         Output Voltage Current Transient         Positive Step Change in Output Current         Negative Step Change in Output Current         Settling Time (within 1% Vout nominal)         Turn-On Transient         Start-Up Time, From On/Off Control         Start-Up Time, From Input         Output Capacitance         EFFICIENCY         100% Load         60% Load         IsoLATION CHARACTERISTICS         Input to Output	lo=lo, min to lo, max Vin=18V to 75V Tc=-40°C to 85°C Over sample load, line and temperature 5Hz to 20MHz bandwidth Vin=48V, Full Load, 10µF ceramic Vin=48V, Full Load, 10µF ceramic Vin=18V to75V Output Voltage 10% Low 48Vin, 10µF ceramic, 0.1A/µs	52.38	±15 ±20 ±50		mV mV mV
Over Load         Over Line         Over Temperature         Total Output Voltage Range         Output Voltage Ripple and Noise         Peak-to-Peak         RMS         Operating Output Current Range         Output Voltage Ripple and Noise         Peak-to-Peak         RMS         Operating Output Current Range         Output Over Current Protection(hiccup mode)         DYNAMIC CHARACTERISTICS         Output Voltage Current Transient         Positive Step Change in Output Current         Negative Step Change in Output Current         Settling Time (within 1% Vout nominal)         Turn-On Transient         Start-Up Time, From On/Off Control         Start-Up Time, From Input         Output Capacitance         EFFICIENCY         100% Load         60% Load         IsoLATION CHARACTERISTICS         Input to Output	Vin=18V to 75V Tc=-40°C to 85°C Over sample load, line and temperature 5Hz to 20MHz bandwidth Vin=48V, Full Load, 10µF ceramic Vin=48V, Full Load, 10µF ceramic Vin=18V to75V Output Voltage 10% Low 48Vin, 10µF ceramic, 0.1A/µs	0	±20 ±50	55.62	mV mV
Over Line         Over Temperature         Total Output Voltage Range         Output Voltage Ripple and Noise         Peak-to-Peak         RMS         Operating Output Current Range         Output Voer Current Protection(hiccup mode)         DYNAMIC CHARACTERISTICS         Output Voltage Current Transient         Positive Step Change in Output Current         Settling Time (within 1% Vout nominal)         Turn-On Transient         Start-Up Time, From On/Off Control         Start-Up Time, From Input         Output Capacitance         EFFICIENCY         100% Load         60% Load         Input to Output	Vin=18V to 75V Tc=-40°C to 85°C Over sample load, line and temperature 5Hz to 20MHz bandwidth Vin=48V, Full Load, 10µF ceramic Vin=48V, Full Load, 10µF ceramic Vin=18V to75V Output Voltage 10% Low 48Vin, 10µF ceramic, 0.1A/µs	0	±20 ±50	55.62	mV mV
Total Output Voltage Range         Output Voltage Ripple and Noise         Peak-to-Peak         RMS         Operating Output Current Range         Output Over Current Protection(hiccup mode)         DYNAMIC CHARACTERISTICS         Output Voltage Current Transient         Positive Step Change in Output Current         Negative Step Change in Output Current         Statt-Up Time (within 1% Vout nominal)         Turn-On Transient         Start-Up Time, From On/Off Control         Start-Up Time, From Input         Output Capacitance         EFFICIENCY         100% Load         60% Load         Input to Output	Over sample load, line and temperature 5Hz to 20MHz bandwidth Vin=48V, Full Load, 10µF ceramic Vin=48V, Full Load, 10µF ceramic Vin=18V to75V Output Voltage 10% Low 48Vin, 10µF ceramic, 0.1A/µs	0	160	55.62	
Output Voltage Ripple and Noise         Peak-to-Peak         RMS         Operating Output Current Range         Output Over Current Protection(hiccup mode)         DYNAMIC CHARACTERISTICS         Output Voltage Current Transient         Positive Step Change in Output Current         Negative Step Change in Output Current         Settling Time (within 1% Vout nominal)         Turn-On Transient         Start-Up Time, From On/Off Control         Start-Up Time, From Input         Output Capacitance         EFFICIENCY         100% Load         60% Load         Input to Output	5Hz to 20MHz bandwidth Vin=48V, Full Load, 10µF ceramic Vin=48V, Full Load, 10µF ceramic Vin=18V to75V Output Voltage 10% Low 48Vin, 10µF ceramic, 0.1A/µs	0		55.62	V
Peak-to-Peak         RMS         Operating Output Current Range         Output Over Current Protection(hiccup mode)         DYNAMIC CHARACTERISTICS         Output Voltage Current Transient         Positive Step Change in Output Current         Negative Step Change in Output Current         Settling Time (within 1% Vout nominal)         Turn-On Transient         Start-Up Time, From On/Off Control         Start-Up Time, From Input         Output Capacitance         EFFICIENCY         100% Load         60% Load         Input to Output	Vin=48V, Full Load, 10µF ceramic Vin=48V, Full Load, 10µF ceramic Vin=18V to75V Output Voltage 10% Low 48Vin, 10µF ceramic, 0.1A/µs				
RMS         Operating Output Current Range         Output Over Current Protection(hiccup mode)         DYNAMIC CHARACTERISTICS         Output Voltage Current Transient         Positive Step Change in Output Current         Negative Step Change in Output Current         Settling Time (within 1% Vout nominal)         Turn-On Transient         Start-Up Time, From On/Off Control         Start-Up Time, From Input         Output Capacitance         EFFICIENCY         100% Load         60% Load         IsoLATION CHARACTERISTICS         Input to Output	Vin=48V, Full Load, 10µF ceramic Vin=18V to75V Output Voltage 10% Low 48Vin, 10µF ceramic, 0.1A/µs				mV
Operating Output Current Range         Output Over Current Protection(hiccup mode)         DYNAMIC CHARACTERISTICS         Output Voltage Current Transient         Positive Step Change in Output Current         Negative Step Change in Output Current         Settling Time (within 1% Vout nominal)         Turn-On Transient         Start-Up Time, From On/Off Control         Start-Up Time, From Input         Output Capacitance         EFFICIENCY         100% Load         60% Load         IsoLATION CHARACTERISTICS         Input to Output	Vin=18V to75V Output Voltage 10% Low 48Vin, 10µF ceramic, 0.1A/µs		00		mV
Output Over Current Protection(hiccup mode)         DYNAMIC CHARACTERISTICS         Output Voltage Current Transient         Positive Step Change in Output Current         Negative Step Change in Output Current         Settling Time (within 1% Vout nominal)         Turn-On Transient         Start-Up Time, From On/Off Control         Start-Up Time, From Input         Output Capacitance         EFFICIENCY         100% Load         60% Load         IsoLATION CHARACTERISTICS         Input to Output	Output Voltage 10% Low 48Vin, 10µF ceramic, 0.1A/µs	3.3		3	A
Output Voltage Current Transient         Positive Step Change in Output Current         Negative Step Change in Output Current         Settling Time (within 1% Vout nominal)         Turn-On Transient         Start-Up Time, From On/Off Control         Start-Up Time, From Input         Output Capacitance         EFFICIENCY         100% Load         60% Load         IsoLATION CHARACTERISTICS         Input to Output				4.5	А
Positive Step Change in Output Current         Negative Step Change in Output Current         Settling Time (within 1% Vout nominal)         Turn-On Transient         Start-Up Time, From On/Off Control         Start-Up Time, From Input         Output Capacitance         EFFICIENCY         100% Load         60% Load         IsoLATION CHARACTERISTICS         Input to Output					
Negative Step Change in Output Current         Settling Time (within 1% Vout nominal)         Turn-On Transient         Start-Up Time, From On/Off Control         Start-Up Time, From Input         Output Capacitance         EFFICIENCY         100% Load         60% Load         ISOLATION CHARACTERISTICS         Input to Output			450		
Settling Time (within 1% Vout nominal) Turn-On Transient Start-Up Time, From On/Off Control Start-Up Time, From Input Output Capacitance EFFICIENCY 100% Load 60% Load ISOLATION CHARACTERISTICS Input to Output	50% lo.max to 75% lo.max 75% lo.max to 50% lo.max		450 350		mV mV
Turn-On Transient       Start-Up Time, From On/Off Control         Start-Up Time, From Input       Output Capacitance         Output Capacitance       EFFICIENCY         100% Load       60% Load         SOLATION CHARACTERISTICS       Input to Output	10% lo.max to 00% lo.max		200		μs
Start-Up Time, From Input         Output Capacitance         EFFICIENCY         100% Load         60% Load         ISOLATION CHARACTERISTICS         Input to Output					
Output Capacitance         EFFICIENCY         100% Load         60% Load         ISOLATION CHARACTERISTICS         Input to Output			70		mS
EFFICIENCY 100% Load 60% Load ISOLATION CHARACTERISTICS Input to Output			90		mS
100% Load       60% Load       ISOLATION CHARACTERISTICS       Input to Output	Full load; 5% overshoot of Vout at startup	0		3300	μF
60% Load ISOLATION CHARACTERISTICS Input to Output	Vin=48V		93.5		%
Input to Output	Vin=48V		93.0		%
Input to heatspreader				2828	Vdc
				2828	Vdc
Output to heatspreader		40		2828	Vdc
Isolation Resistance		10	4000		MΩ pF
FEATURE CHARACTERISTICS			4000		pi
Switching Frequency			300		KHz
ON/OFF Control, Negative Remote On/Off logic					
Logic Low (Module On)	Von/off	-0.7		0.8	V
Logic High (Module Off)	Von/off	2.5		15	V
ON/OFF Control, Positive Remote On/Off logic					
Logic Low (Module Off)	Von/off	-0.7		0.8	V
Logic High (Module On)	Von/off	2.5		15	V
ON/OFF Current (for both remote on/off logic) Leakage Current (for both remote on/off logic)	Ion/off at Von/off=0V Logic High, Von/off=5V			1.5	mA
Output Voltage Trim Range	Pout $\leq$ max rated power, lo $\leq$ lo.max	-10		10	%
	•				
Output Over-Voltage Protection	% of nominal Vout	115		140	%
GENERAL SPECIFICATIONS					
	0% of Io, max; Ta=25°C, airflow rate=300LFM		10.3		Mhours
Weight	With heat spreader		96		grams
	Refer to Figure 20 for Hot spot 1 location		136		°C
(48)	(in,80% lo, 200LFM,Airflow from Vin- to Vin+)				
Over-Temperature Shutdown (With heat spreader) (48)			123		°C
Over-Temperature Shutdown (NTC resistor)	Refer to Figure 23 for Hot spot 2 location in,80% lo, 200LFM,Airflow from Vin- to Vin+)		130		°C





**Figure 1:** Efficiency vs. load current for minimum, nominal, and maximum input voltage at 25°C.

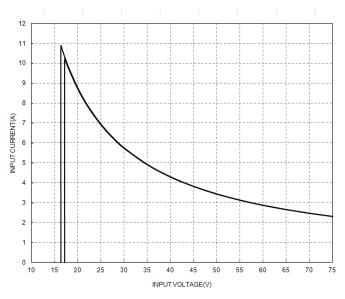
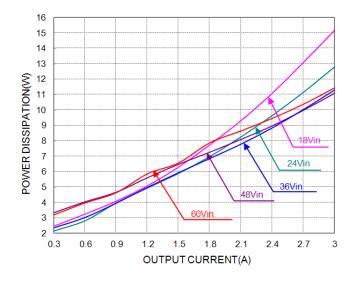


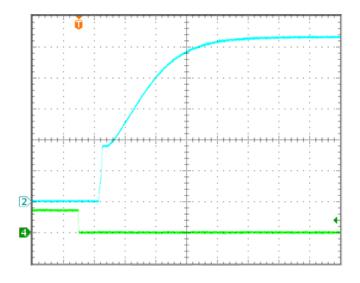
Figure 3: Full load input characteristics at room temperature.



*Figure 2:* Power dissipation vs. load current for minimum, nominal, and maximum input voltage at 25°C.

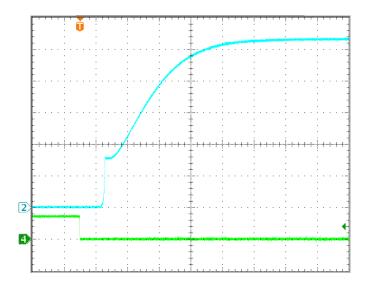


### For Negative Remote On/Off Logic

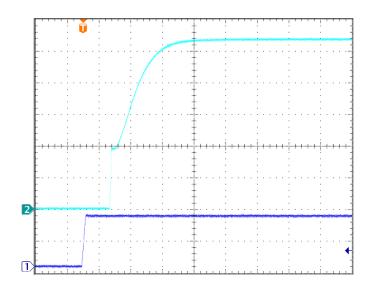


*Figure 4:* Turn-on transient at zero load current (20ms/div). Vin=48V. Top Trace: Vout; 10V/div; Bottom Trace: ON/OFF input: 5V/div.

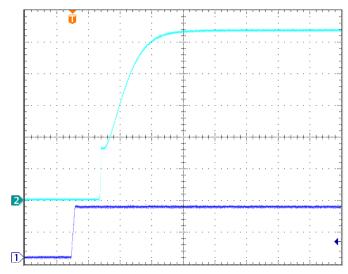
For Input Voltage Start up



*Figure 5:* Turn-on transient at full load current (20ms/div). Vin=48V. Top Trace: Vout: 10V/div; Bottom Trace: ON/OFF input: 5V/div.

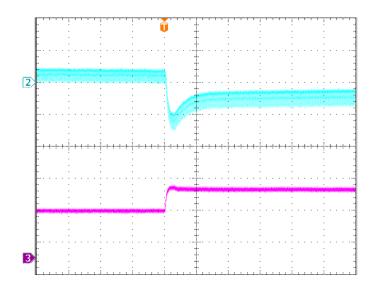


*Figure 6:* Turn-on transient at zero load current (40 ms/div). Top Trace: Vout; 10V/div; Bottom Trace: input voltage: 30V/div

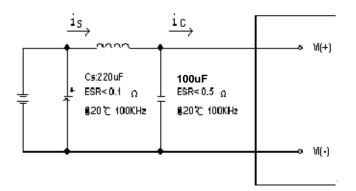


*Figure 7*: Turn-on transient at full load current (40 ms/div). Top Trace: Vout; 10V/div; Bottom Trace: input voltage:30V/div.



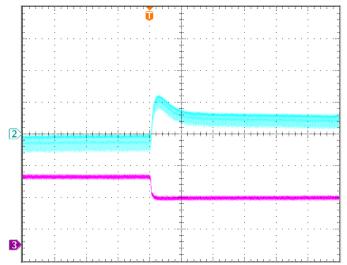


**Figure 8:** Output voltage response to step-change in load current (50%-75% of Io, max; di/dt =  $0.1A/\mu$ s; Vin=48V). Load cap:  $10\mu$ F ceramic capacitor. Top Trace: Vout (0.3V/div, 200us/div), Bottom Trace: lout (1A/div). Scope measurement should be made using a BNC cable (length shorter than 20 inches). Position the load between 51 mm to 76 mm (2 inches to 3 inches) from the module

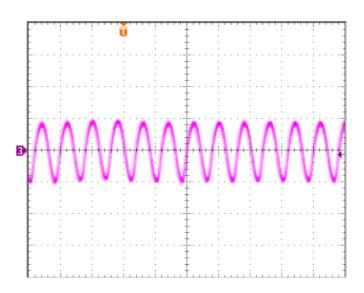


*Figure 10:* Test set-up diagram showing measurement points for Input Terminal Ripple Current and Input Reflected Ripple Current.

Note: Measured input reflected-ripple current with a simulated source Inductance ( $L_{TEST}$ ) of 12  $\mu$ H. Capacitor Cs offset possible battery impedance. Measure current as shown above.

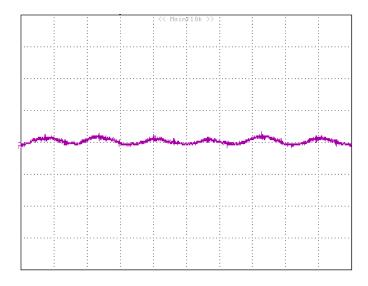


**Figure 9:** Output voltage response to step-change in load current (75%-50% of Io, max; di/dt =  $0.1A/\mu$ s; Vin=48V). Load cap:  $10\mu$ F ceramic capacitor. Top Trace: Vout (0.3V/div, 200us/div), Bottom Trace: lout (1A/div). Scope measurement should be made using a BNC cable (length shorter than 20 inches). Position the load between 51 mm to 76 mm (2 inches to 3 inches) from the module

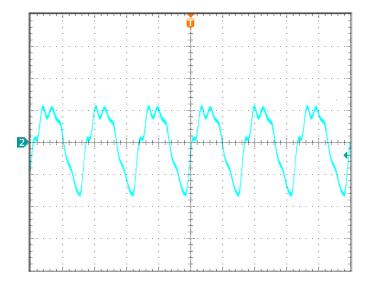


**Figure 11:** Input Terminal Ripple Current, *i*<sub>c</sub>, at max output current and nominal input voltage with  $12\mu$ H source impedance and  $100\mu$ F electrolytic capacitor (500 mA/div, 4us/div).





**Figure 12:** Input reflected ripple current,  $i_s$ , through a  $12\mu$ H source inductor at nominal input voltage and max load current (20mA/div , 2us/div).



**Figure 14:** Output voltage ripple at nominal input voltage and max load current (50 mV/div, 2us/div) Load capacitance: 10μF ceramic capacitor Bandwidth: 20 MHz.

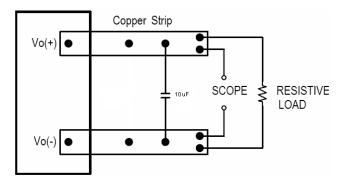
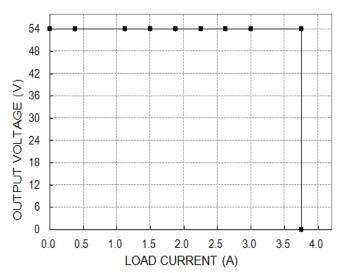


Figure 13: Output voltage noise and ripple measurement test setup.



*Figure 15:* Output voltage vs. load current showing typical current limit curves and converter shutdown points.



#### **DESIGN CONSIDERATIONS**

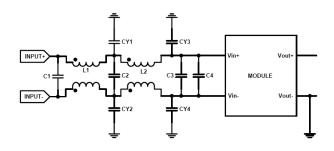
#### Input Source Impedance

The impedance of the input source connecting to the DC/DC power modules will interact with the modules and affect the stability. A low ac-impedance input source is recommended. If the source inductance is more than a few  $\mu$ H, we advise 220 $\mu$ F electrolytic capacitor (ESR < 0.7  $\Omega$  at 100 kHz) mounted close to the input of the module to improve the stability.

#### Layout and EMC Considerations

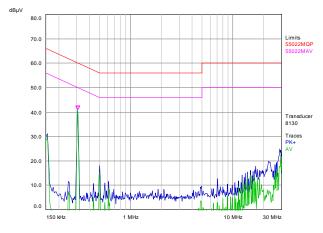
Delta's DC/DC power modules are designed to operate in a wide variety of systems and applications. For design assistance with EMC compliance and related PWB layout issues, please contact Delta's technical support team. An external input filter module is available for easier EMC compliance design. Below is the reference design for an input filter tested with H36SA54003 to meet class B in CISSPR 22.

#### **Schematic and Components List**



C1=C2= 4.4uF ceramic capacitor C3=0.1uF ceramic capacitor CY1=CY2=CY3=CY4=10nF C4=100uF Electrolytic capacitor L1=L2=0.473mH common chock(Pulse P0502)

#### Test Result: Vin=48V, Io=3A



#### **Safety Considerations**

The power module must be installed in compliance with the spacing and separation requirements of the end-user's safety agency standard, i.e., IEC 62368-1: 2014 (2nd edition), EN 62368-1: 2014 (2nd edition), UL 62368-1, 2nd Edition, 2014-12-01 and CSA C22.2 NO. 62368-1-14, 2nd Edition, UL60950-1, CSA C22.2 NO. 60950-1 2nd and IEC 60950-1 2nd : 2005 and EN 60950-1 2nd: 2006+A11+A1: 2010, if the system in which the power module is to be used must meet safety agency requirements.

Basic insulation based on 75 Vdc input is provided between the input and output of the module for the purpose of applying insulation requirements when the input to this DC-to-DC converter is identified as TNV-2 or SELV. An additional evaluation is needed if the source is other than TNV-2 or SELV.

When the input source is SELV circuit, the power module meets SELV (safety extra-low voltage) requirements. If the input source is a hazardous voltage which is greater than 60 Vdc and less than or equal to 75 Vdc, for the module's output to meet SELV requirements, all of the following must be met:

- The input source must be insulated from the ac mains by reinforced or double insulation.
- The input terminals of the module are not operator accessible.
- A SELV reliability test is conducted on the system where the module is used, in combination with the module, to ensure that under a single fault, hazardous voltage does not appear at the module's output.

When installed into a Class II equipment (without grounding), spacing consideration should be given to the end-use installation, as the spacing between the module and mounting surface have not been evaluated.

The power module has extra-low voltage (ELV) outputs when all inputs are ELV.

This power module is not internally fused. To achieve optimum safety and system protection, an input line fuse is highly recommended. The safety agencies require a normal-blow fuse with 30A maximum rating to be installed in the ungrounded lead. A lower rated fuse can be used based on the maximum inrush transient energy and maximum input current.

#### **Soldering and Cleaning Considerations**

Post solder cleaning is usually the final board assembly process before the board or system undergoes electrical testing. Inadequate cleaning and/or drying may lower the reliability of a power module and severely affect the



reliability of a power module and severely affect the finished circuit board assembly test. Adequate cleaning and/or drying is especially important for un-encapsulated and/or open frame type power modules. For assistance on appropriate soldering and cleaning procedures, please contact Delta's technical support team.

### **FEATURES DESCRIPTIONS**

#### **Over-Current Protection**

The modules include an internal output over-current protection circuit, which will endure current limiting for an unlimited duration during output overload. If the output current exceeds the OCP set point, the modules will shut down (hiccup mode).

The modules will try to restart after shutdown. If the overload condition still exists, the module will shut down again. This restart trial will continue until the overload condition is corrected.

#### **Over-Voltage Protection**

The modules include an internal output over-voltage protection circuit, which monitors the voltage on the output terminals. If this voltage exceeds the over-voltage set point, the protection circuit will constrain the max duty cycle to limit the output voltage, if the output voltage continuously increases the modules will shut down, and then restart after a hiccup-time (hiccup mode).

#### **Over-Temperature Protection**

The over-temperature protection consists of circuitry that provides protection from thermal damage. If the temperature exceeds the over-temperature threshold the module will shut down.The module will restart after the temperature is within specification.

#### Remote On/Off

The remote on/off feature on the module can be either negative or positive logic. Negative logic turns the module on during a logic low and off during a logic high. Positive logic turns the modules on during a logic high and off during a logic low.

Remote on/off can be controlled by an external switch between the on/off terminal and the Vi (-) terminal. The switch can be an open collector or open drain. For negative logic if the remote on/off feature is not used, please short the on/off pin to Vi (-). For positive logic if the remote on/off feature is not used, please leave the on/off pin to floating.

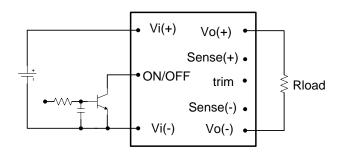


Figure 16: Remote on/off implementation

#### **Output Voltage Adjustment (TRIM)**

To increase or decrease the output voltage set point, connect an external resistor between the TRIM pin and the Vout+ or Vout-. The TRIM pin should be left open if this feature is not used.

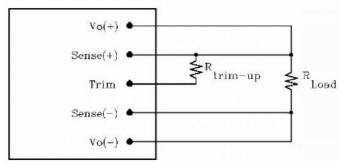


Figure 17: Circuit configuration for trim-up (increase output

voltage)

If the external resistor is connected between the TRIM and Vout (+) pins, the output voltage set point increases (Fig. 17). The external resistor value required to obtain a percentage of output voltage change  $\triangle$ % is defined as:

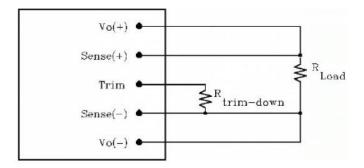
$$Rtrim - up = \frac{\operatorname{Vo}(100 + \Delta)}{1.24\Delta} - \frac{100}{\Delta} - 2(K\Omega)$$

Ex. When Trim-up +10% (54V×1.1=59.4V)

$$Rtrim - up = \frac{54 \times (100 + 10)}{1.24 \times 10} - \frac{100}{10} - 2 = 467(K\Omega)$$



#### **Output Voltage Adjustment (TRIM)**



*Figure 18:* Circuit configuration for trim-down (decrease output voltage)

If the external resistor is connected between the TRIM and Vout (-), the output voltage set point decreases (Fig. 18). The external resistor value required to obtain a percentage of output voltage change  $\triangle$ % is defined as

$$Rtrim - down = \left[\frac{100}{\Delta} - 2\right] (K\Omega)$$

Ex. When Trim-down -10% (54V×0.9=48.6V)

$$Rtrim - down = \left[\frac{100}{10} - 2\right] (K\Omega) = 8(K\Omega)$$

When using remote sense and trim, the output voltage of the module is usually increased, which increases the power output of the module with the same output current.

Care should be taken to ensure that the maximum output power of the module remains at or below the maximum rated power.

### THERMAL CONSIDERATIONS

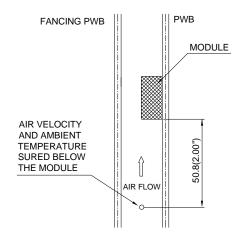
Thermal management is an important part of the system design. To ensure proper, reliable operation, sufficient cooling of the power module is needed over the entire temperature range of the module. Convection cooling is usually the dominant mode of heat transfer.

Hence, the choice of equipment to characterize the thermal performance of the power module is a wind tunnel.

#### **Thermal Testing Setup**

Delta's DC/DC power modules are characterized in heated vertical wind tunnels that simulate the thermal environments encountered in most electronics equipment. This type of equipment commonly uses vertically mounted circuit cards in cabinet racks in which the power modules are mounted.

The following figure shows the wind tunnel characterization setup. The power module is mounted on a 185mmX185mm,70µm (2Oz),6 layers test PWB and is vertically positioned within the wind tunnel. The space between the neighboring PWB and the top of the power module is constantly kept at 6.35mm (0.25").



Note: Wind Tunnel Test Setup Figure Dimensions are in millimeters and (Inches)

Figure 19: Wind tunnel test setup

#### **Thermal Derating**

Heat can be removed by increasing airflow over the module. To enhance system reliability, the power module should always be operated below the maximum operating temperature. If the temperature exceeds the maximum module temperature, reliability of the unit may be affected.



### THERMAL CURVES (WITHOUT HEAT SPREADER)

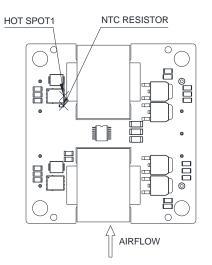


Figure 20: \* Hot spot 1& NTC resistor temperature measured points. The allowed maximum hot spot 1 temperature is defined at 120  ${\rm °C}$ 

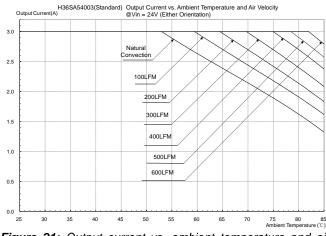
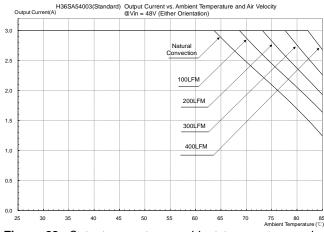


Figure 21: Output current vs. ambient temperature and air velocity @Vin=24V(Either Orientation, without heat spreader)



**Figure 22:** Output current vs. ambient temperature and air velocity @Vin=48V(Either Orientation, without heat spreader)

### THERMAL CURVES (WITH HEAT SPREADER)

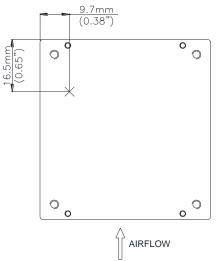
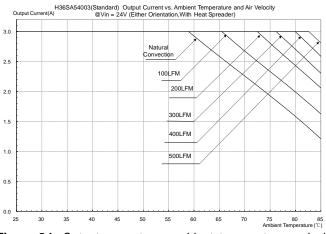
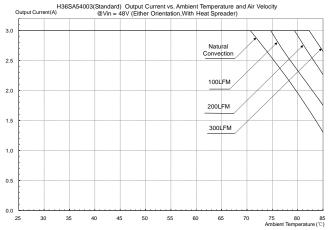
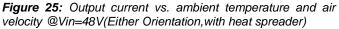


Figure 23: \* Hot spot 2 temperature measured point. The allowed maximum hot spot 2 temperature is defined at 108  ${}^\circ\!\!C$ 



*Figure 24:* Output current vs. ambient temperature and air velocity @Vin=24V(Either Orientation, with heat spreader)

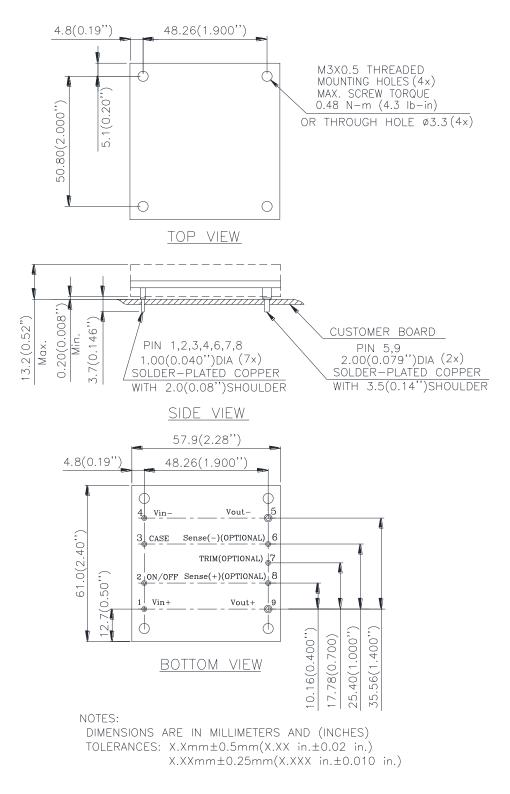






#### **MECHANICAL DRAWING**

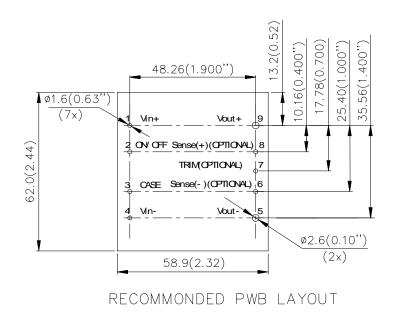
For modules with through-hole pins and the optional heatspreader, they are intended for wave soldering assembly onto system boards; please do not subject such modules through reflow temperature profile.



Note: All pins are copper alloy with matte Tin(Pb free) plated over Nickel under plating.



### **RECOMMENDED LAYOUT**



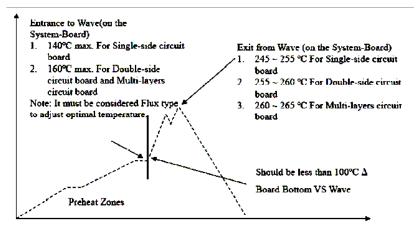
#### Soldering method

Generally, as the most common mass soldering method for the solder attachment, wave soldering is used for through-hole power modules and reflow soldering is used for surface-mount ones. Delta recommended soldering methods and process parameters are provided in this document for solder attachment of power modules onto system board. SAC305 is the suggested lead-free solder alloy for all soldering methods. The soldering temperature profile presented in this document is based on SAC305 solder alloy.

Reflow soldering is not a suggested method for through-hole power modules due to many process and reliability concerns. If you have this kind of application requirement, please contact Delta sales or FAE for further confirmation.

#### Wave Soldering (Lead-free)

Delta's power modules are designed to be compatible with single-wave or dual wave soldering. The suggested soldering process must keep the power module's internal temperature below the critical temperature of 217°C continuously. The recommended wave-soldering profile is shown below:



Note: The temperature is measured on solder joint of pins of power module.



The typical recommended (for double-side circuit board) preheat temperature is  $115+/-10^{\circ}$ C on the top side (component side) of the circuit board. The circuit-board bottom-side preheat temperature is typically recommended to be greater than  $135^{\circ}$ C and preferably within  $100^{\circ}$ C of the solder-wave temperature. A maximum recommended preheat up rate is  $3^{\circ}$ C /s. A maximum recommended solder pot temperature is  $255+/-5^{\circ}$ C with solder-wave dwell time of  $3\sim6$  seconds. The cooling down rate is typically recommended to be  $6^{\circ}$ C/s maximum.

### Hand Soldering (Lead Free)

Hand soldering is the least preferred method because the amount of solder applied, the time the soldering iron is held on the joint, the temperature of the iron, and the temperature of the solder joint are variable. The recommended hand soldering guideline is listed in Table below. The suggested soldering process must keep the power module's internal temperature below the critical temperature of 217°C continuously.

Parameter	Single-side	Double-side	Multi-layers	
	Circuit Board	Circuit Board	Circuit Board	
Soldering Iron Wattage	90	90	90	
Tip Temperature	385+/-10°C	420+/-10°C	420+/-10°C	
Soldering Time	$2 \sim 6$ seconds	$4 \sim 10$ seconds	$4\sim 10 \ seconds$	



PART NUMBERING SYSTEM										
Н	36	S	Α	540	03	N	N	F		н
Form	Input	Number of	Product	Output	Output	ON/OFF	Pin	Pin		
Factor	Voltage	Outputs	Series	Voltage	Current	Logic	Length	assigment		
H - Half	36 -	S - Single	A -	540 - 54V	03 - 3A	N - Negative	K - 0.110"	F - RoHS 6/6	н	Heat spreader(threaded hole), NO SENSE,NO TRIM
Brick	18V~75V		Series			P - Positive	N - 0.145"	(Lead Free)	с	Heat spreader(threaded hole), With SENSE,With TRIM
			number				R - 0.170"		G	Heat spreader (through hole), With SENSE,With TRIM

MODEL LIST								
MODEL NAME	INPUT		OUTPUT		EFF @ 100% LOAD			
H36SA54003NNFH	18V~75V	11A	54V	ЗA	93.5% @ 48Vin			
H36SA54003NNFC	18V~75V	11A	54V	ЗA	93.5% @ 48Vin			
H36SA54003NNFG	18V~75V	11A	54V	ЗA	93.5% @ 48Vin			

Default remote on/off logic is negative and pin length is 0.145".

For different remote on/off logic and pin length, please refer to part numbering system above or contact your local sales office. For modules with through-hole pins and the optional heatspreader, they are intended for wave soldering assembly onto system boards; please do not subject such modules through reflow temperature profile.

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#### WARRANTY

Delta offers a two (2) year limited warranty. Complete warranty information is listed on our web site or is available upon request from Delta.

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